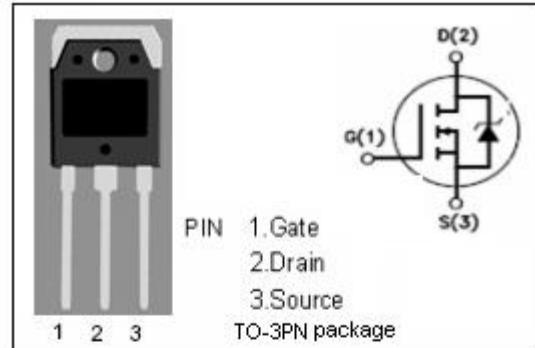


isc N-Channel MOSFET Transistor

2SK899

DESCRIPTION

- Drain Current – $I_D=18A$ @ $T_c=25^\circ C$
- Drain Source Voltage-
 - : $V_{DSS}=500V$ (Min)
- Fast Switching Speed
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

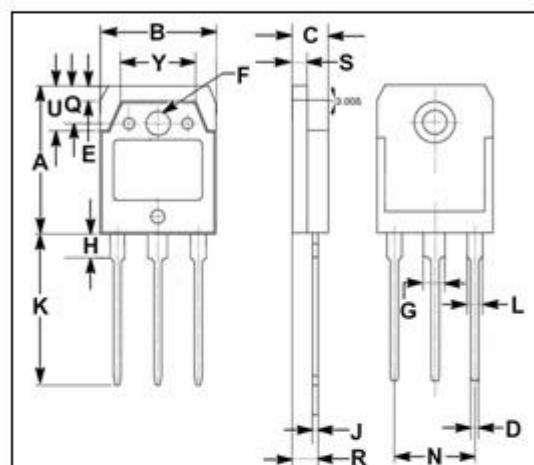


APPLICATIONS

- Switching regulators
- UPS
- DC-DC converters
- General purpose power amplifier

ABSOLUTE MAXIMUM RATINGS($T_a=25^\circ C$)

SYMBOL	PARAMETER	VALUE	UNIT
V_{DSS}	Drain-Source Voltage ($V_{GS}=0$)	500	V
V_{GS}	Gate-Source Voltage	± 20	V
I_D	Drain Current-continuous@ $TC=25^\circ C$	18	A
$I_{D(puls)}$	Pulsed Drain Current	72	A
P_{tot}	Total Dissipation@ $TC=25^\circ C$	125	W
T_j	Max. Operating Junction Temperature	150	$^\circ C$
T_{stg}	Storage Temperature Range	-55~150	$^\circ C$



DIM	mm	
	MIN	MAX
A	19.60	20.10
B	15.50	15.70
C	4.70	4.90
D	0.90	1.10
E	1.90	2.10
F	3.40	3.60
G	2.90	3.20
H	3.20	3.40
J	0.595	0.605
K	20.00	20.70
L	1.90	2.20
N	10.89	10.91
Q	4.90	5.10
R	3.35	3.45
S	1.995	2.100
U	5.90	6.10
Y	9.90	10.10

THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
$R_{th\ j-c}$	Thermal Resistance, Junction to Case	1.0	$^\circ C/W$
$R_{th\ j-a}$	Thermal Resistance, Junction to Ambient	35	$^\circ C/W$

isc N-Channel Mosfet Transistor**2SK899****• ELECTRICAL CHARACTERISTICS ($T_c=25^\circ\text{C}$)**

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
$V_{(\text{BR})\text{DSS}}$	Drain-Source Breakdown Voltage	$V_{GS}=0$; $I_D=1\text{mA}$	500			V
$V_{GS(\text{TH})}$	Gate Threshold Voltage	$V_{DS}=10\text{V}$; $I_D=1\text{mA}$	2.1	3.0	4.0	V
$R_{DS(\text{ON})}$	Drain-Source On-stage Resistance	$V_{GS}=10\text{V}$; $I_D=8\text{A}$		0.28	0.33	Ω
I_{GSS}	Gate Source Leakage Current	$V_{GS} = \pm 20\text{V}$; $V_{DS}=0$			± 100	nA
I_{DSS}	Zero Gate Voltage Drain Current	$V_{DS}=500\text{V}$; $V_{GS}=0$			500	uA
G_{fs}	Forward Transconductance	$V_{DS}=25\text{V}$; $I_D=8\text{A}$	8			S
t_{on}	Turn-on time	$V_{GS}=30\text{V}$; $I_D=2.8\text{A}$ $R_L=50\ \Omega$		130	195	ns
t_{off}	Turn-off time			330	430	ns
V_{SD}	Diode Forward Voltage	$I_F=36\text{A}$; $V_{GS}=0$		1.0	1.7	V